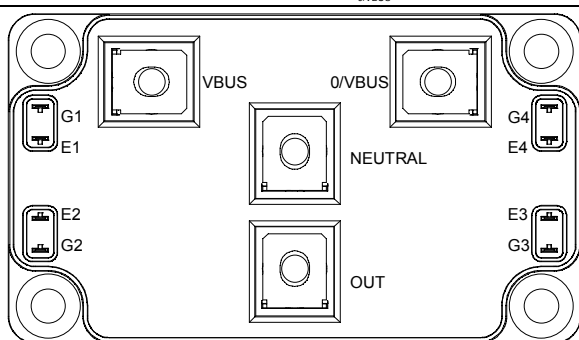
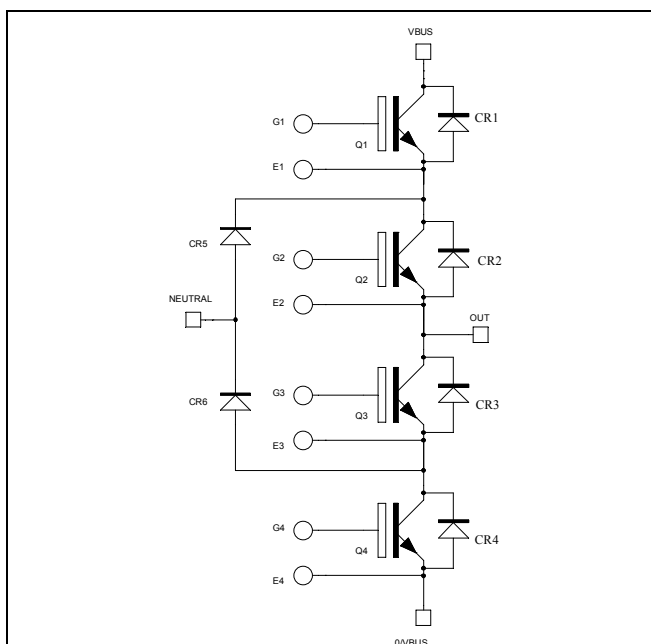


**Three level inverter  
Trench + Field Stop IGBT3  
Power Module**

**$V_{CES} = 650V$   
 $I_C = 300A @ T_c = 80^\circ C$**


**Application**

- Solar converter
- Uninterruptible Power Supplies

**Features**

- Trench + Field Stop IGBT Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

**Benefits**

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

**All ratings @  $T_j = 25^\circ C$  unless otherwise specified**

**Q1 to Q4 Absolute maximum ratings**

Symbol	Parameter	Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage	650	V
$I_C$	Continuous Collector Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
$I_{CM}$	Pulsed Collector Current	$T_c = 25^\circ C$	600
$V_{GE}$	Gate - Emitter Voltage	$\pm 20$	V
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	935
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^\circ C$	600A @ 600V



**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**Q1 to Q4 Electrical Characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$			350	$\mu A$
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $I_C = 300A$		1.5 1.7	1.9	V
		$T_j = 25^\circ C$ $T_j = 150^\circ C$				
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 5 mA$	5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			800	nA

**Q1 to Q4 Dynamic Characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>	<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
$C_{ies}$	Input Capacitance	$V_{GE} = 0V$		18.4		nF
$C_{oes}$	Output Capacitance	$V_{CE} = 25V$		1.16		
$C_{res}$	Reverse Transfer Capacitance	$f = 1MHz$		0.54		
$Q_G$	Gate charge	$V_{GE} = \pm 15V, I_C = 300A$ $V_{CE} = 300V$		3.2		$\mu C$
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $25^\circ C$ ) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_C = 300A$ $R_G = 2.2\Omega$		115		ns
$T_r$	Rise Time			45		
$T_{d(off)}$	Turn-off Delay Time			225		
$T_f$	Fall Time			55		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $150^\circ C$ ) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_C = 300A$ $R_G = 2.2\Omega$		130		ns
$T_r$	Rise Time			50		
$T_{d(off)}$	Turn-off Delay Time			300		
$T_f$	Fall Time			70		
$E_{on}$	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	1.7 3		mJ
$E_{off}$	Turn off Energy	$I_C = 300A$ $R_G = 2.2\Omega$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	8.2 10.6		
$I_{sc}$	Short Circuit data	$V_{GE} \leq 15V ; V_{Bus} = 360V$ $t_p \leq 6\mu s ; T_j = 150^\circ C$		1500		A
$R_{thJC}$	Junction to Case Thermal Resistance				0.16	$^\circ C/W$

**CR1 to CR4 diode ratings and characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			650			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =650V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C			150 400	μA
I <sub>F</sub>	DC Forward Current		T <sub>c</sub> = 80°C		200		A
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 200A V <sub>GE</sub> = 0V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		1.6 1.5	2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 200A V <sub>R</sub> = 300V di/dt = 2800A/μs	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		125 220		ns
Q <sub>rr</sub>	Reverse Recovery Charge		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		9.4 19.8		μC
E <sub>rr</sub>	Reverse Recovery Energy		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		2.2 4.8		mJ
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.39	°C/W

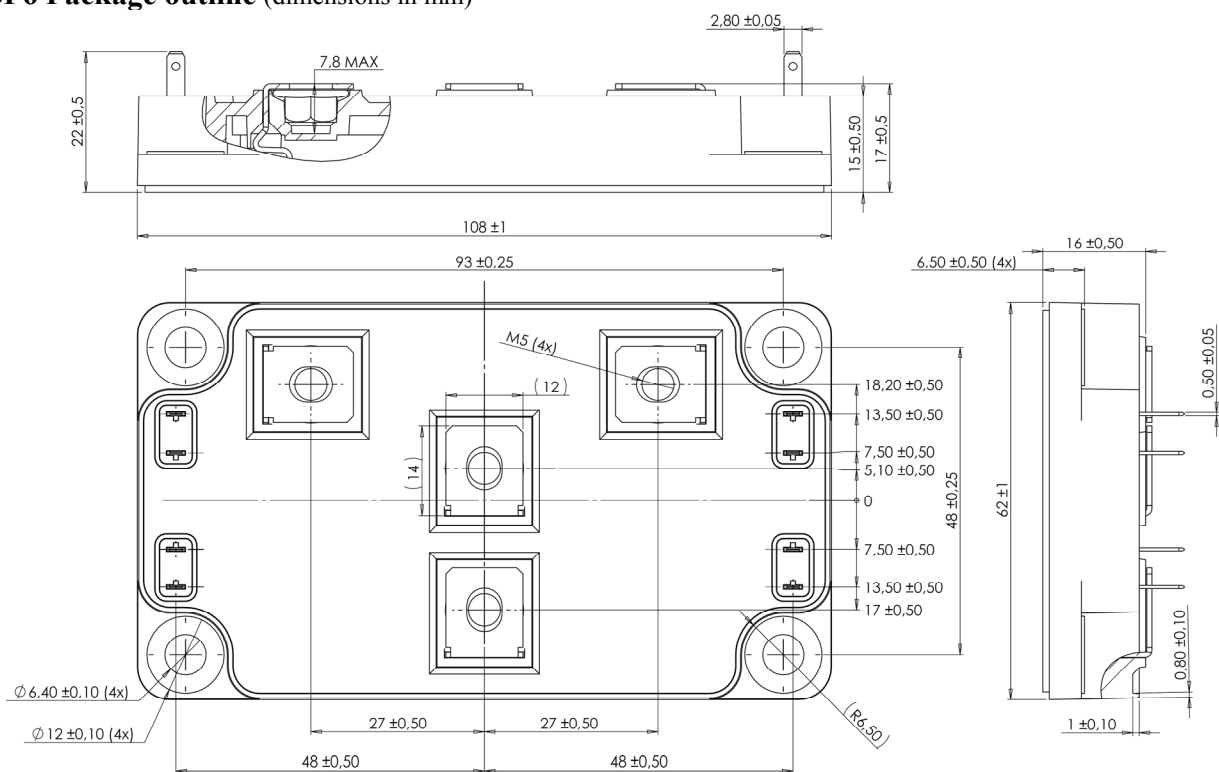
**CR5 & CR6 diode ratings and characteristics**

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			650			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =650V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C			150 400	μA
I <sub>F</sub>	DC Forward Current		T <sub>c</sub> = 80°C		300		A
V <sub>F</sub>	Diode Forward Voltage	I <sub>F</sub> = 300A V <sub>GE</sub> = 0V	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		1.6 1.5	2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 300A V <sub>R</sub> = 300V di/dt = 4000A/μs	T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		130 225		ns
Q <sub>rr</sub>	Reverse Recovery Charge		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		13.7 29		μC
E <sub>rr</sub>	Reverse Recovery Energy		T <sub>j</sub> = 25°C T <sub>j</sub> = 150°C		3.2 7		mJ
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.29	°C/W

**Thermal and package characteristics**

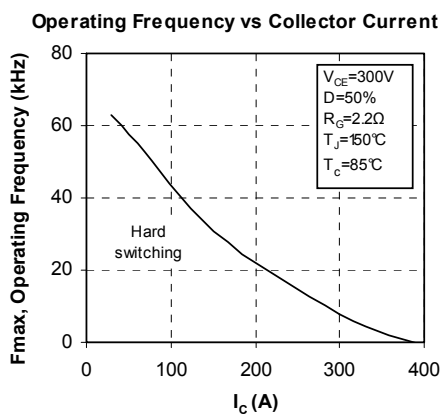
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V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range			-40		175	°C
T <sub>STG</sub>	Storage Temperature Range			-40		125	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					300	g

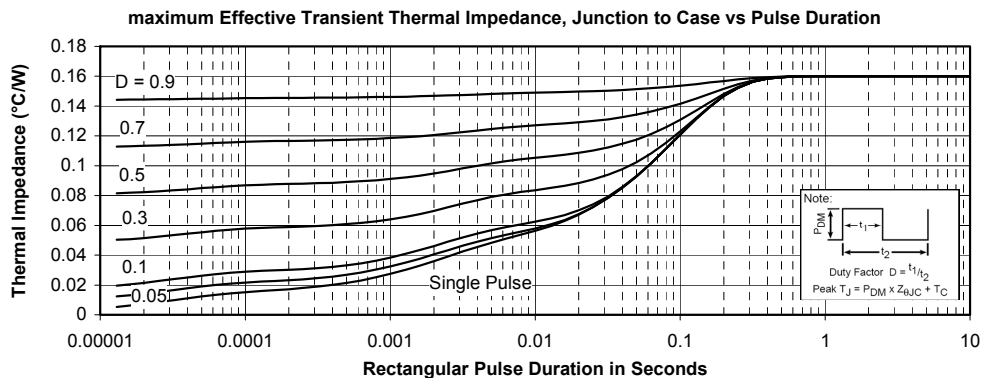
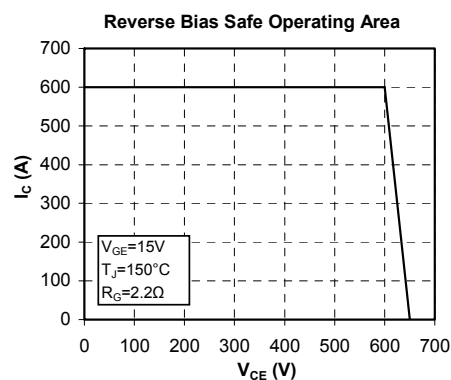
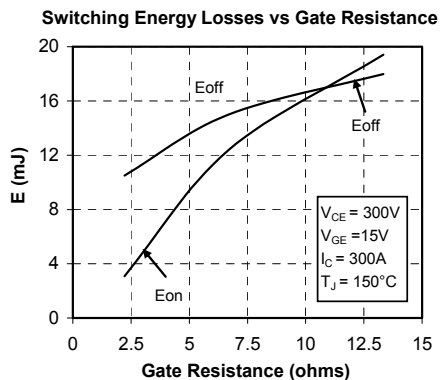
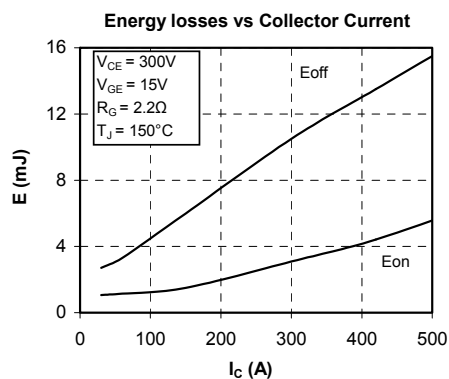
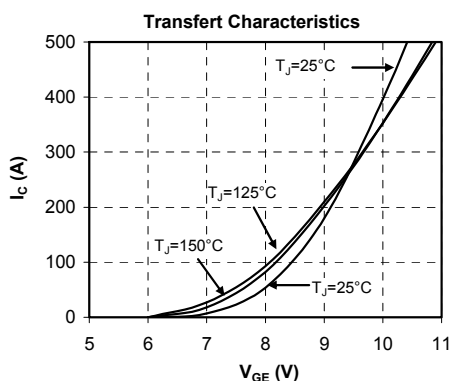
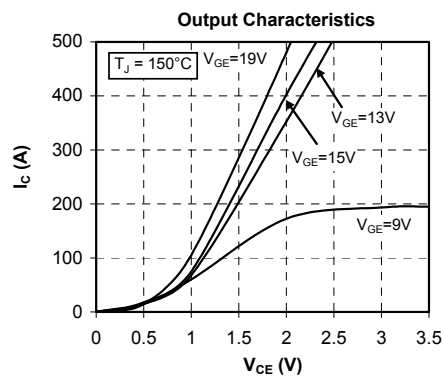
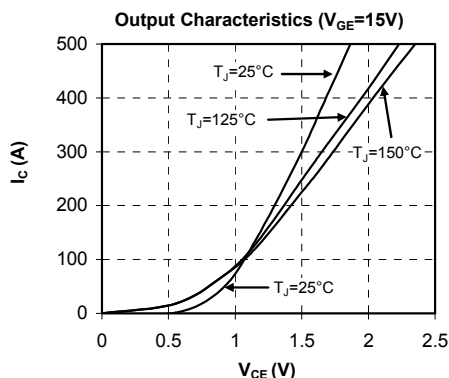
## SP6 Package outline (dimensions in mm)

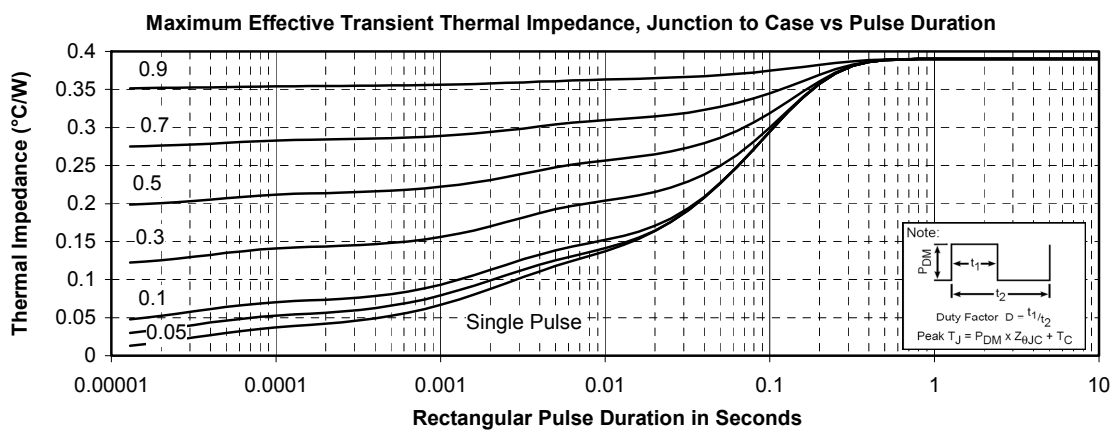
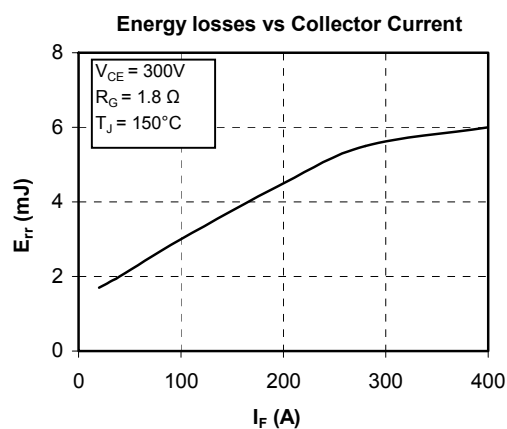
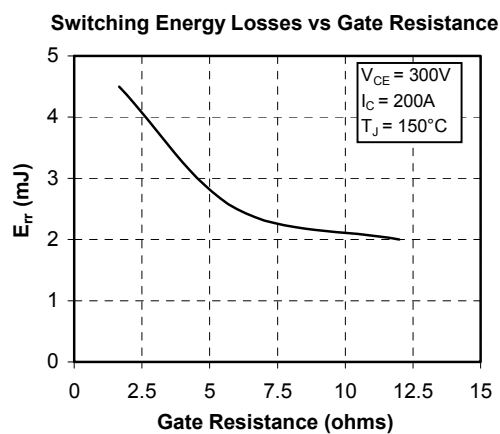
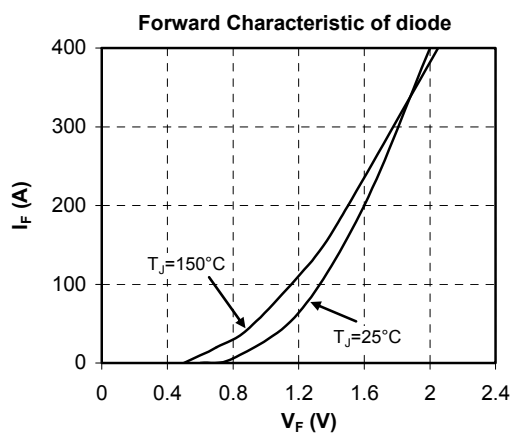


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

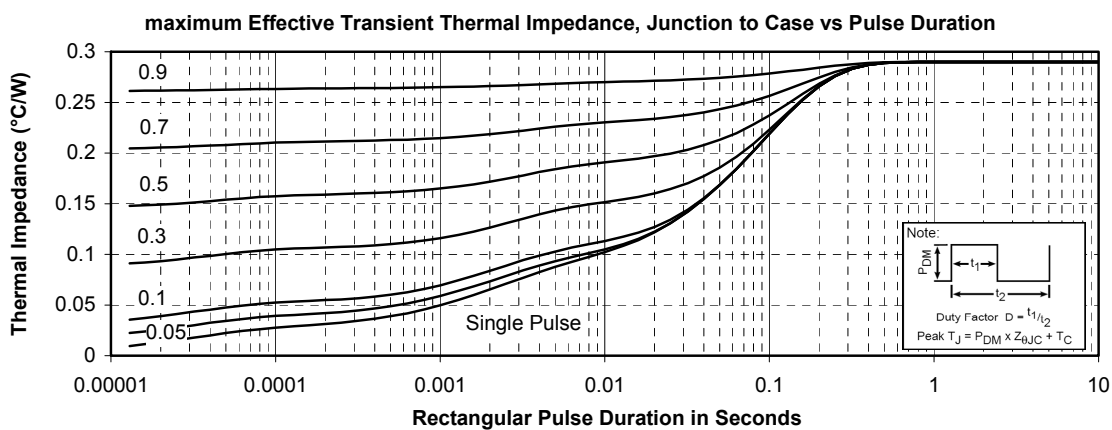
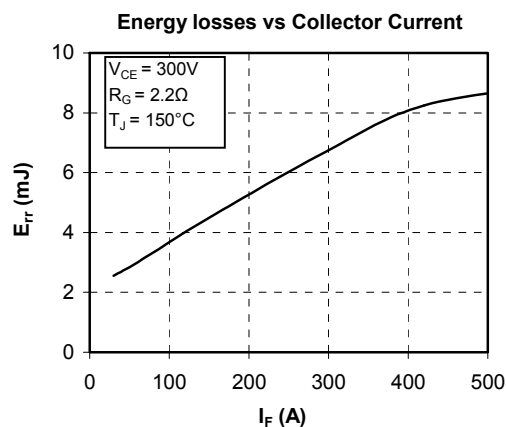
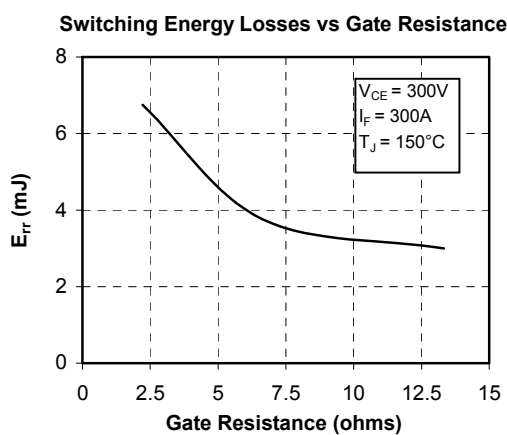
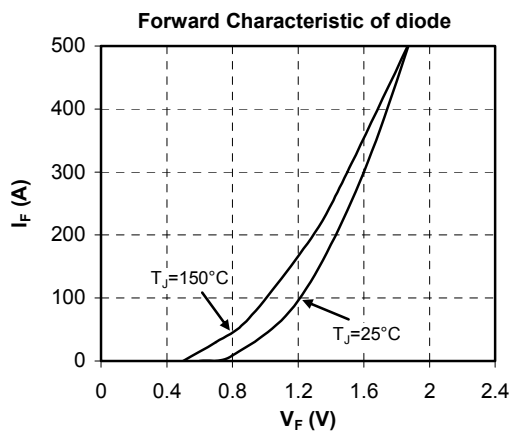
## Q1 to Q4 Typical performance curve





**CR1 to CR4 Typical performance curve**


**CR5 & CR6 Typical performance curve**



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